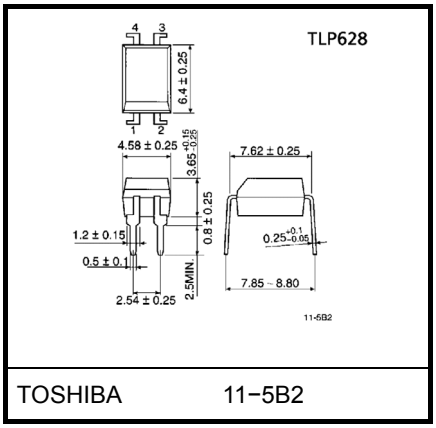
TOSHIBA Photocoupler GaAs Ired & Photo−Transistor

TLP628,TLP628−2,TLP628−4

Programmable Controllers
DC−Output Module
Telecommunication

Unit in mm

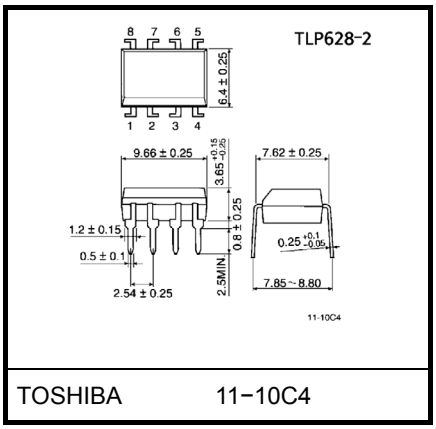


TOSHIBA 11−5B2

Weight: 0.26g

The TOSHIBA TLP628, −2, and −4 consists of a gallium arsenide infrared emitting diode optically coupled to a phototransistor which has a 350V high voltage of collector−emitter breakdown voltage.
The TLP628−2 offers two isolated channels in a eight lead plastic DIP package, while the TLP628−4 provide four isolated channels per package.

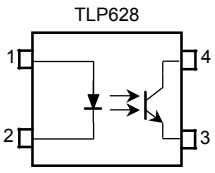
- Collector−emitter voltage: 350 V (min.)
- Current transfer ratio: 50% (min.)
- Isolation voltage: 5000Vrms (min.)
- UL recognized: UL1577, file No. E67349
- BSI approved: BS EN60065:2002, certificate no.7426
  BS EN60950-1:2002, certificate no.7427



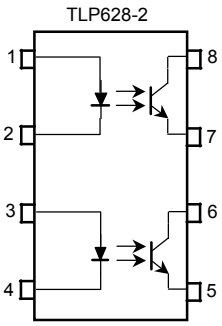
TOSHIBA 11−10C4

Weight: 0.54g

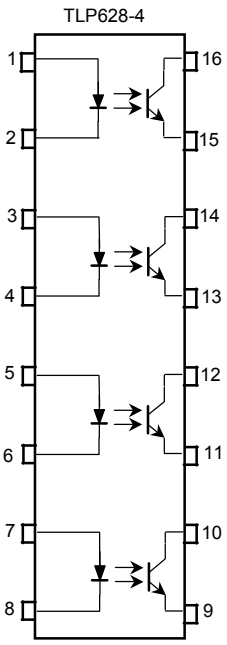
Pin Configurations (top view)



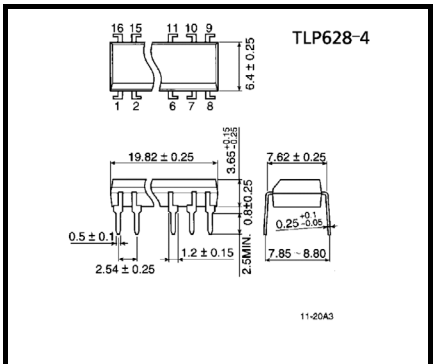
1: Anode
2: Cathode
3: Emitter
4: Collector



1, 3: Anode
2, 4: Cathode
5, 7: Emitter
6, 8: Collector



1, 3, 5, 7: Anode
2, 4, 6, 8: Cathode
9, 11, 13, 15: Emitter
10, 12, 14, 16: Collector



TOSHIBA 11−20A3

Weight: 1.1g

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating		Unit
			TLP628	TLP628−2 TLP628−4	
LED	Forward current	I_F	60	50	mA
	Forward current derating	ΔI_F / °C	−0.7 (Ta ≥ 39°C)	−0.5 (Ta ≥ 25°C)	mA / °C
	Pulse forward current	I_{FP}	1 (100μs pulse, 100pps)		A
	Reverse voltage	V_R	5		V
	Junction temperature	T_j	125		°C
Detector	Collector−emitter voltage	V_{CEO}	350		V
	Emitter−collector voltage	V_{ECO}	7		V
	Collector current	I_C	50		mA
	Collector power dissipation (1 circuit)	P_C	150	100	mW
	Collector power dissipation derating (Ta ≥ 25°C, 1 circuit)	ΔP_C / °C	−1.5	−1.0	mW / °C
	Junction temperature	T_j	125		°C
Storage temperature range		T_{stg}	−55~125		°C
Operating temperature range		T_{opr}	−55~100		°C
Lead soldering temperature		T_{sol}	260 (10s)		°C
Total package power dissipation (1 circuit)		P_T	200	150	mW
Total package power dissipation derating (Ta ≥ 25°C, 1 circuit)		ΔP_T / °C	−2.0	−1.5	mW / °C
Isolation voltage		BV_S	5000 (AC, 1min., R.H. ≤ 60%) (Note 1)		Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{CC}	—	—	200	V
Forward current	I_F	—	16	25	mA
Collector current	I_C	—	—	10	mA
Operating temperature	T_{opr}	−25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	I_F = 10 mA	1.0	1.15	1.3	V
	Reverse current	I_R	V_R = 5 V	—	—	10	μA
	Capacitance	C_T	V = 0, f = 1 MHz	—	30	—	pF
Detector	Collector−emitter breakdown voltage	$V_{(BR)\ CEO}$	I_C = 0.1 mA	350	—	—	V
	Emitter−collector breakdown voltage	$V_{(BR)\ ECO}$	I_E = 0.1 mA	7	—	—	V
	Collector dark current	I_{CEO}	V_{CE} = 300 V	—	10	200	nA
			V_{CE} = 300 V, Ta = 85°C	—	—	50	μA
	Capacitance collector to emitter	C_{CE}	V = 0, f = 1 MHz	—	10	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current transfer ratio	I_C / I_F	I_F = 5 mA, V_{CE} = 5 V	50	—	600	%
		Rank GB	100	—	600	
Saturated CTR	I_C / $I_{F\ (sat)}$	IF = 1 mA, V_{CE} = 0.4 V	—	60	—	%
		Rank GB	30	—	—	
Collector−emitter saturation voltage	$V_{CE\ (sat)}$	I_C = 2.4 mA, I_F = 8 mA	—	—	0.4	V
		I_C = 0.2 mA, I_F = 1 mA	—	0.2	—	
		Rank GB	—	—	0.4	

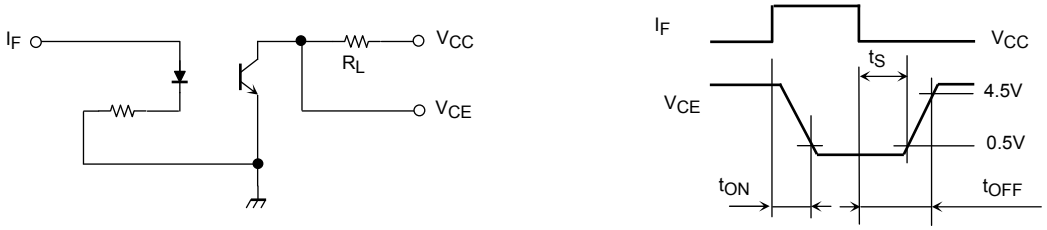
Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	C_S	V_S = 0, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R_S	V_S = 500 V R.H. ≤ 60%	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	5000	—	—	V_{rms}
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	V_{dc}

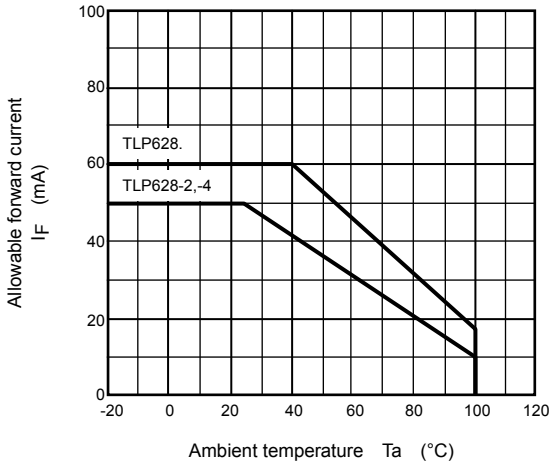
Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Rise time	t_r	V_{CC} = 10 V, I_C = 2 mA AR_L = 100Ω	—	2	—	μs
Fall time	t_f		—	3	—	
Turn−on time	t_{on}		—	3	—	
Turn−off time	t_{off}		—	3	—	
Turn−on time	t_{ON}	R_L = 1.9 kΩ (Fig.1) V_{CC} = 5 V, I_F = 16 mA	—	3	—	μs
Storage time	t_s		—	40	—	
Turn−off time	t_{OFF}		—	90	—	

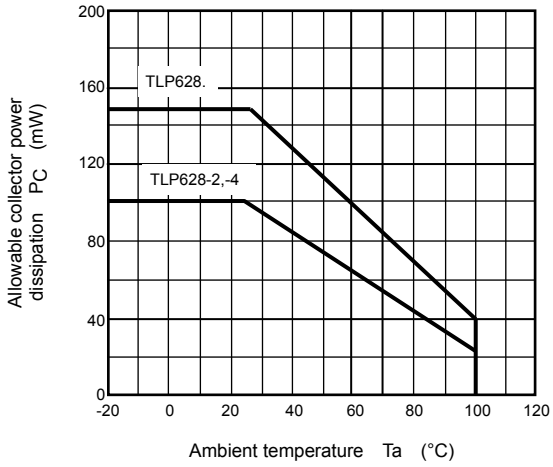
Fig. 1 Switching time test circuit



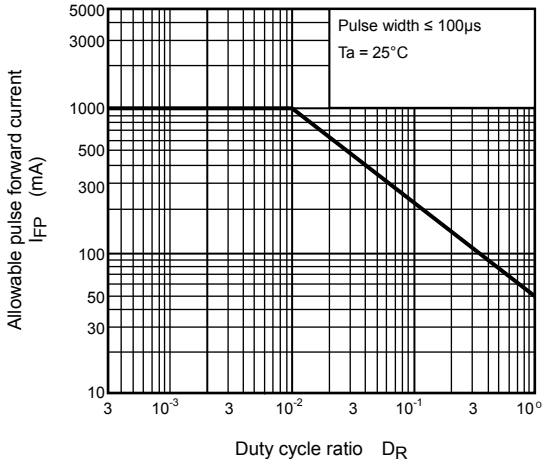
I_F – Ta



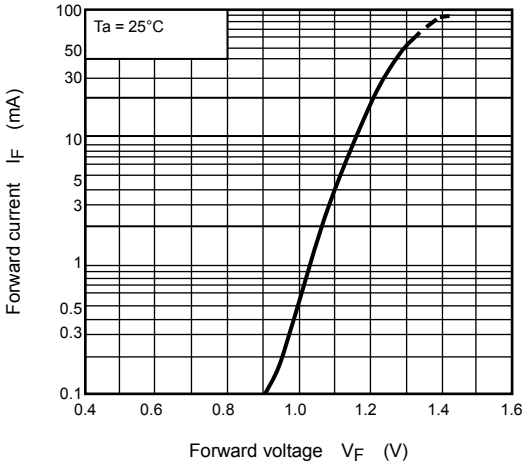
P_C– Ta



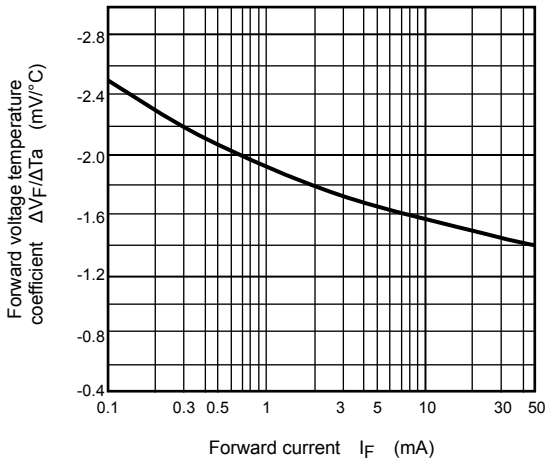
I_{FP} – D_R



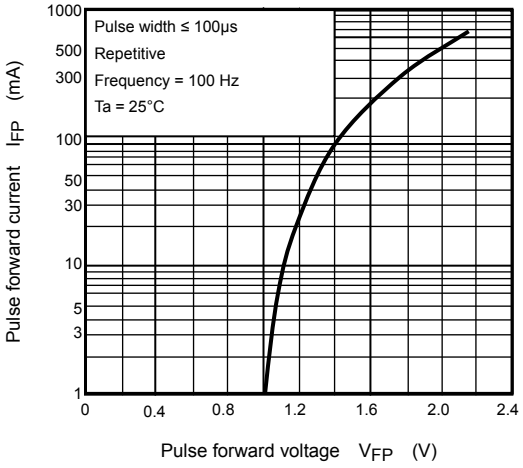
I_F – V_F



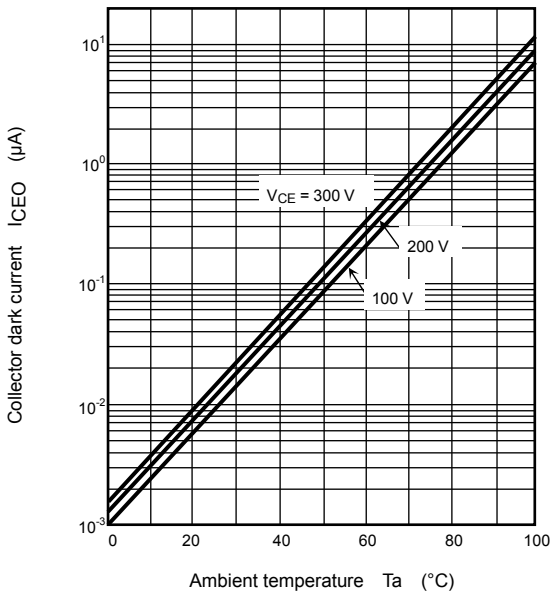
$\Delta V_F/\Delta Ta$ – I_F



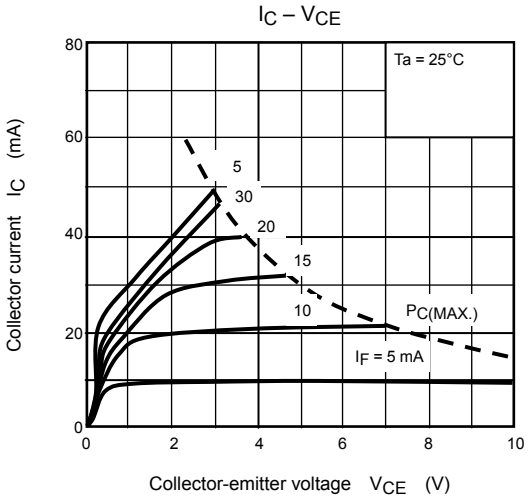
I_{FP} – V_{FP}



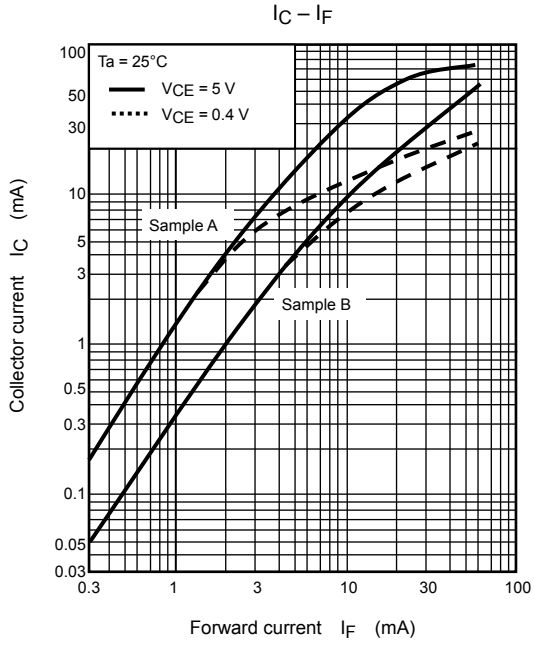
I_D – Ta



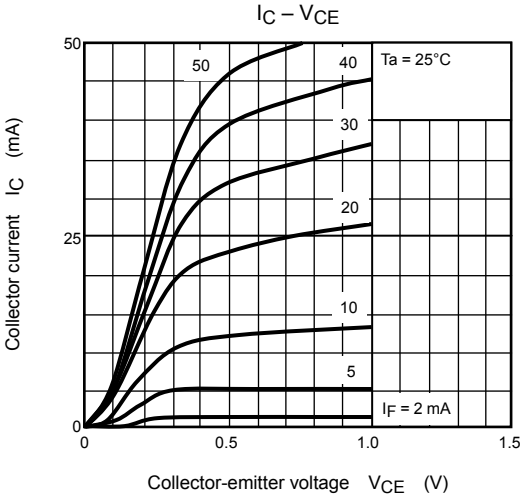
I_C – V_{CE}



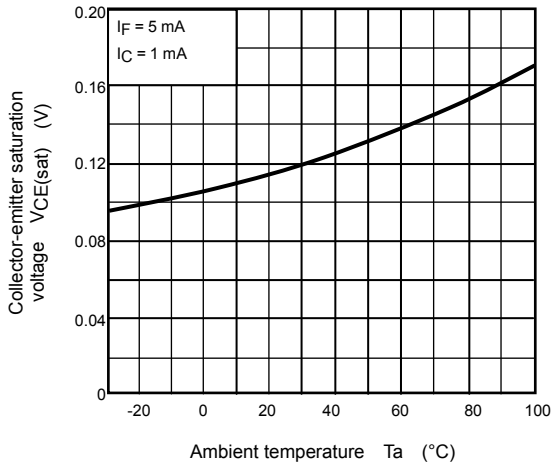
I_C – I_F



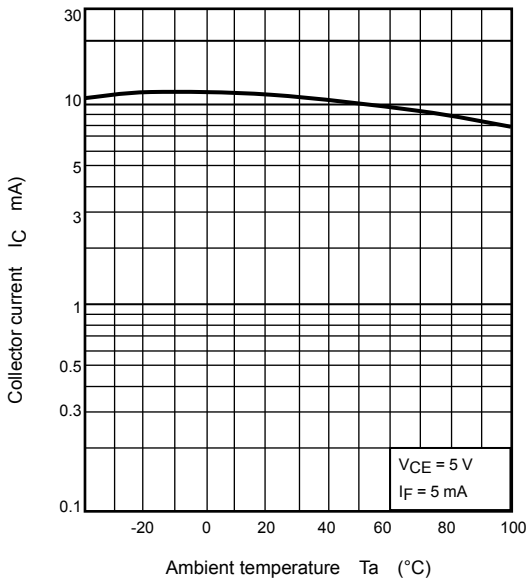
I_C – V_{CE}



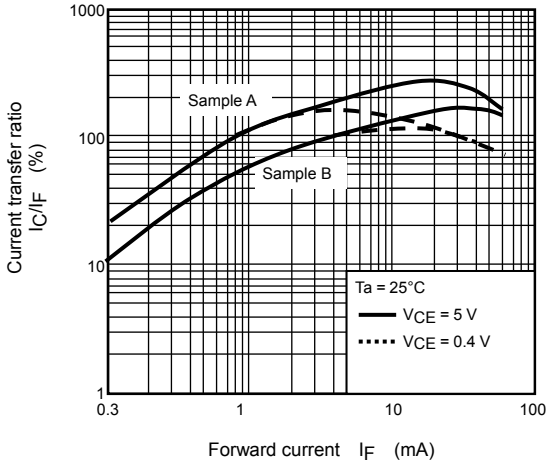
$V_{CE(sat)}$ – Ta



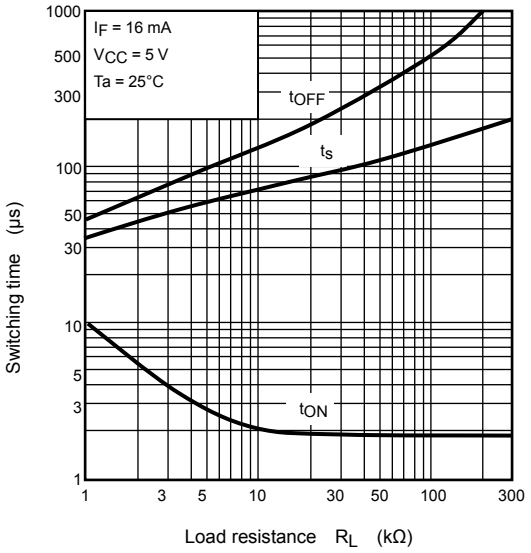
I_C – Ta



I_C / I_F – I_F



Switching Time – R_L



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20070701-EN

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